

Simulation of thin-film quantum dot solar cells with light-trapping in the IR range

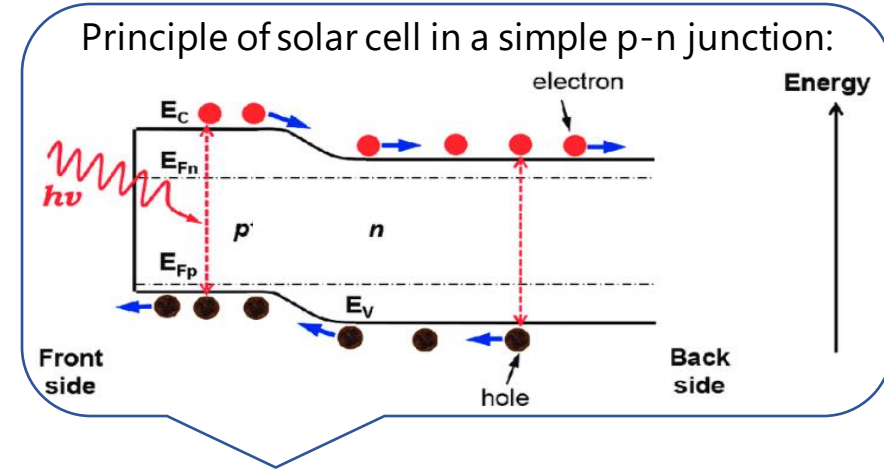
Okada Lab, RCAST, UTokyo

June 12, 2023 - Maia Pécastaings

1- Topic introduction

QD solar cell with light-trapping

- Less material
- Less distance for charge carriers to travel



Simulation of thin-film quantum dot solar cells with light-trapping in the IR range

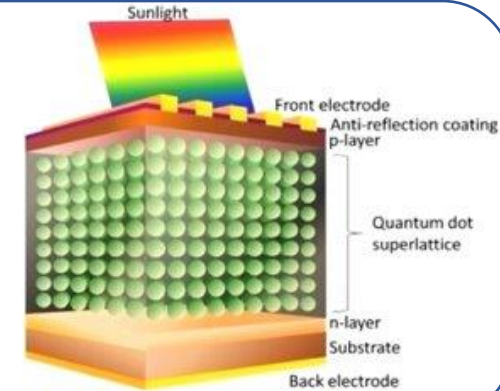
- IR is also interesting: half of the solar spectrum incident on Earth is infrared.
- Requires to be able to absorb photons with lower energy

1- Topic introduction

QD solar cell with light-trapping

quantum dot (QD):
tiny nanostructure. When
made of semiconductor
material, its size
determines which
wavelengths it absorbs.

**p-i-n
quantum dot
solar cell *:**
QD layers
added in
the i-layer to
absorb
photons.

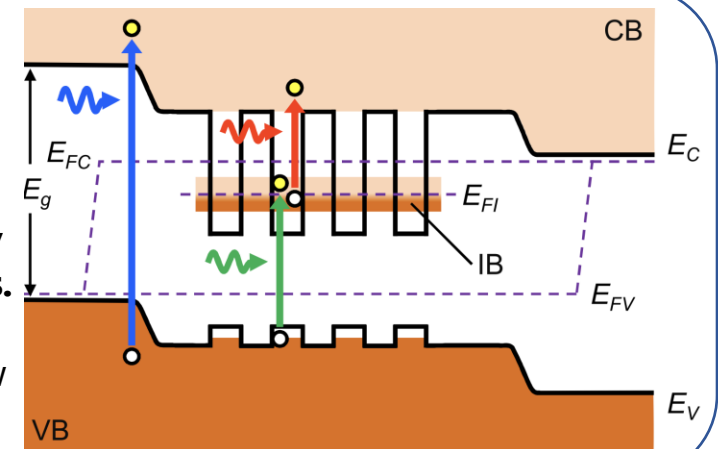


Simulation of thin-film quantum dot solar cells with light-trapping in the IR range

QD solar cells are
**intermediate band
solar cells.**

With the IB, possibility
to **absorb IR photons.**

But in general, too low
occupancy of the IB.



*

i (intrinsic): where electron-hole pairs are created
p (positive): where holes are conducted
n (negative): where electrons are conducted

1- Topic introduction

QD solar cell with light-trapping

Simulation of thin-film quantum dot solar cells with light-trapping in the IR range

Goal: increase the absorption in the quantum dots

$$A_{(\lambda)} = \sum^{N_{stacks}} \frac{1}{2} \epsilon_0 \cdot c \cdot \alpha_{(\lambda)} \cdot d \cdot n_{(\lambda)} \cdot |E_{(z,\lambda)}|^2$$

Stacking multiple layers
Problem: thicker

Absorption coefficient
➤ Increase the QD density
Problem: more defects in the material

Field strength
➤ **Light-trapping strategies**

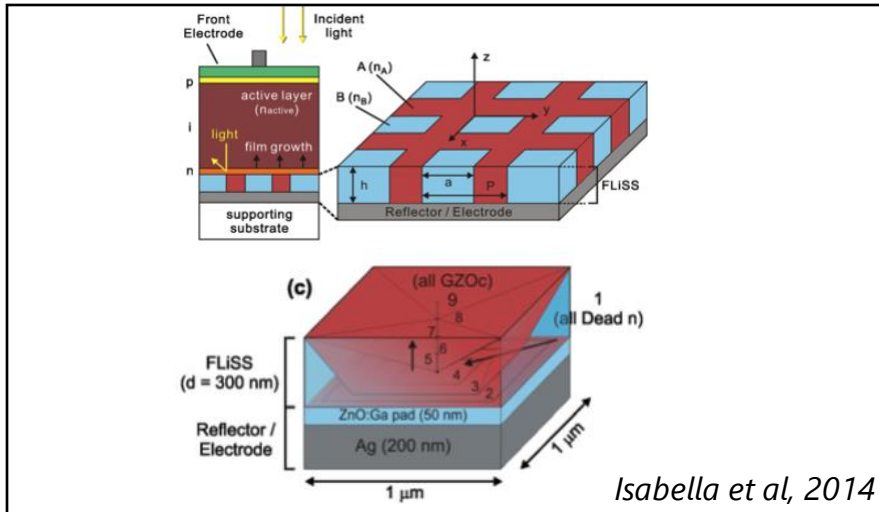
1- Topic introduction

QD solar cell with light-trapping

Goal: increase the absorption in the quantum dots.

Idea: combine two phenomena.

➤ FLISS: **light-scattering**



A back-grating structure composed of materials with very different refractive indexes can act as **light scatterer**.

= Flattened Light Scattering Substrate (FLISS)

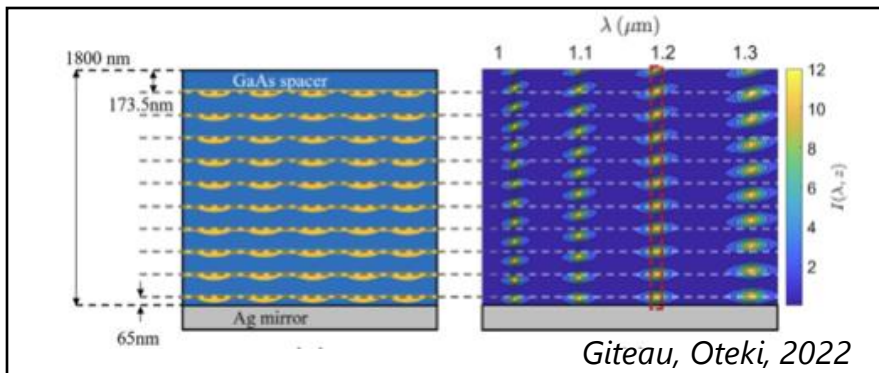
➤ Absorption is increased due to higher electric field in the active layer.

Optimize the back-grating to have maximum E-field enhancement.

And then:

Place the QD layers at the peak positions corresponding to this optimized back-grating.

➤ Ag/Au back mirror: **Fabry-Perot resonance**



The device, between the air layer and the mirror, forms a cavity with **resonance at specific wavelengths**.

➤ Absorption is increased when QD layers are positioned on the resonance peaks of a well-chosen wavelength.

1- Topic introduction

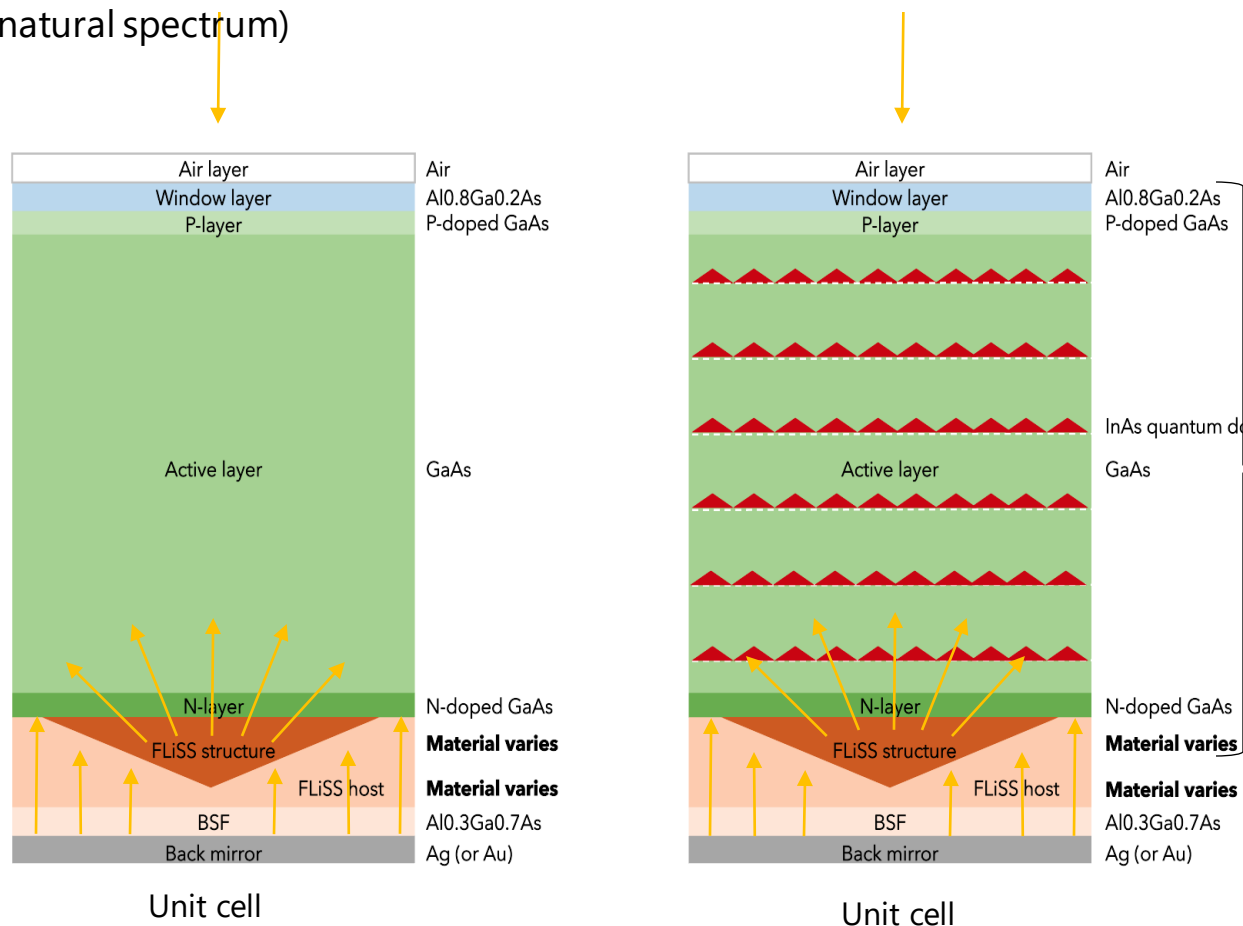
QD solar cell with light-trapping

Goal: increase the absorption in the quantum dots.

In InAs/GaAs QD solar cells with Ag mirror.

For now:

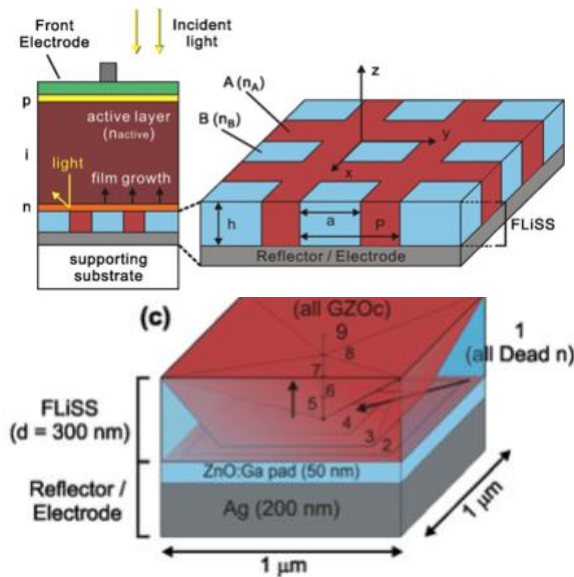
- Incident power 1W (not natural spectrum)
- No quantum dots yet



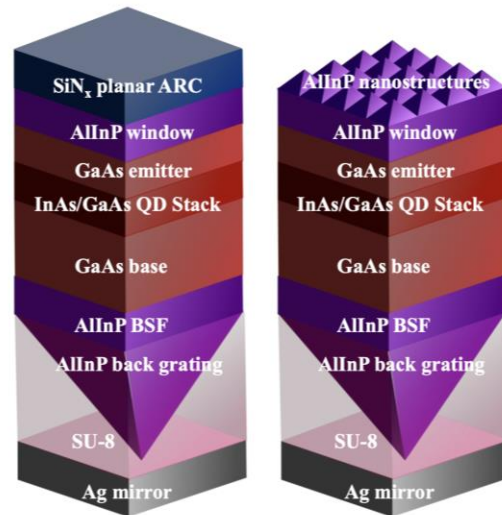
1- Topic introduction

Back-grating pattern

Isabella et al, 2014
In Si solar cell

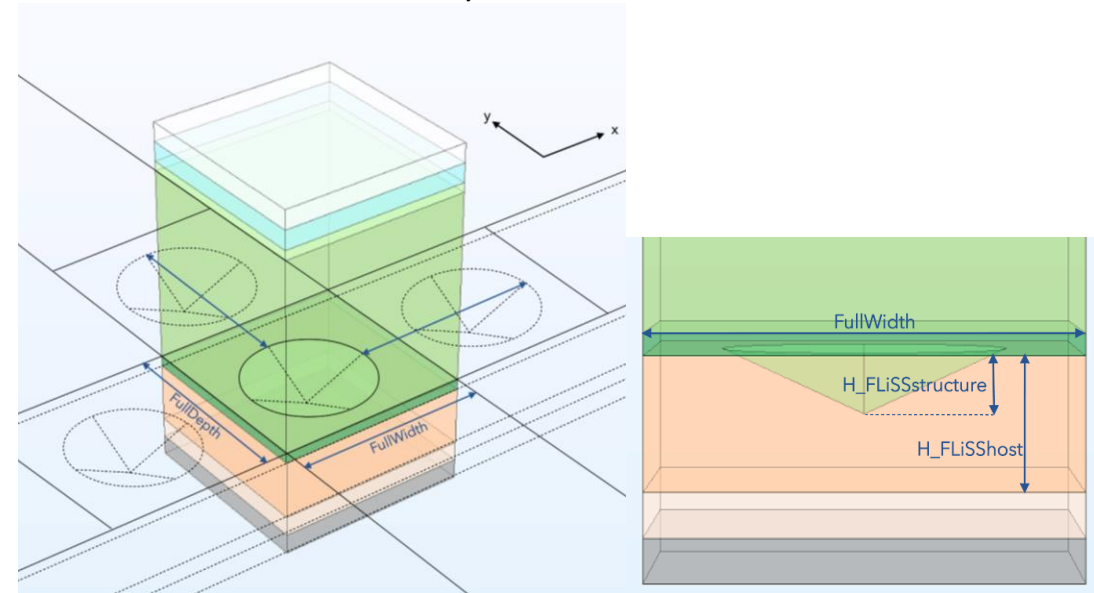


Elsehrawy et al, 2018
In InAs/GaAs QD solar cell



- Structure material: AlInP ←
- Host material: SU-8 ←

In this study
In InAs/GaAs QD solar cell



Explore **two shapes**:

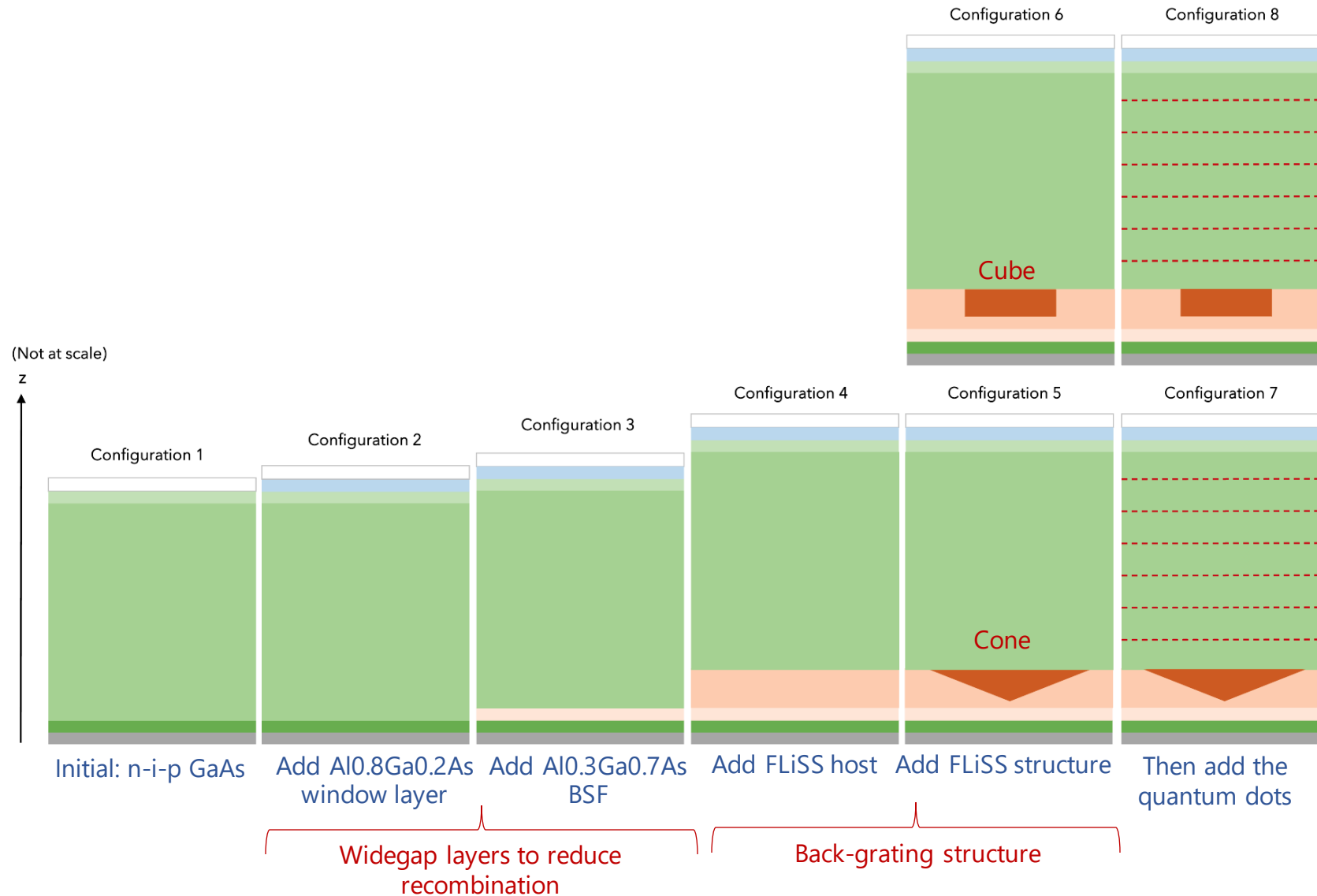
- Inverted cone (truncated or not)
- Cube (parallelepiped with square base)

Vary:

- The structure size and height
- The period of the pattern

2- First simulation results

Simulation steps



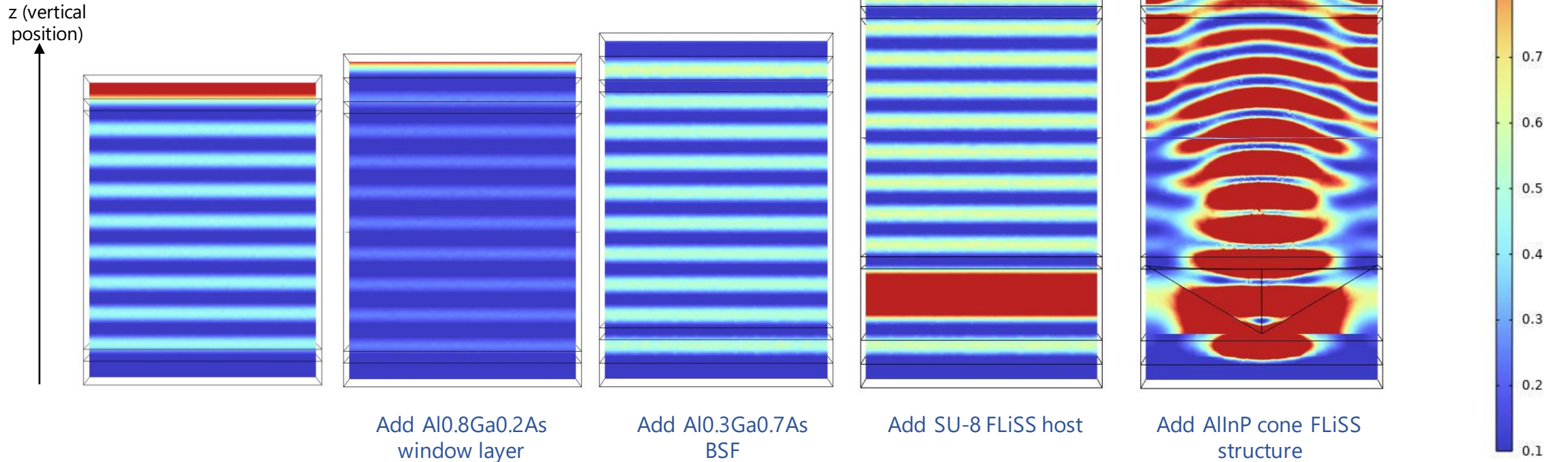
2- First simulation results

E-field distribution in the successive configurations (cone)

Example

Plot of $|E|^2$ at $\lambda = 950$ nm

- SU-8 FLiSS host
- AlInP full cone (radius 500 nm, height 300 nm) as FLiSS structure



One choice of λ is not representative but:

- In general for almost all wavelengths, the FLiSS structure **enhances** and **distorts** the distribution of **the E-field**.
- However, there is a small displacement of the resonance wavelengths.

2- First simulation results

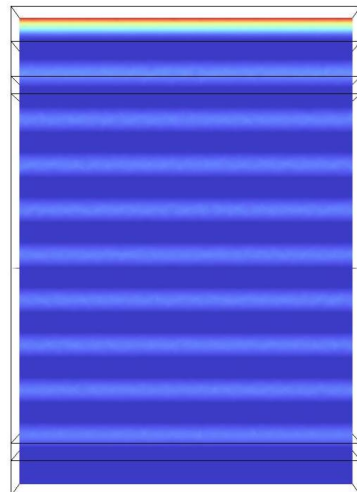
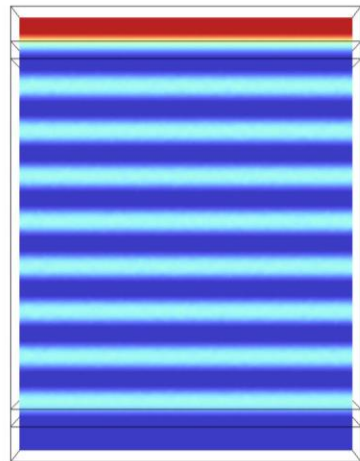
E-field distribution in the successive configurations (cube)

Example

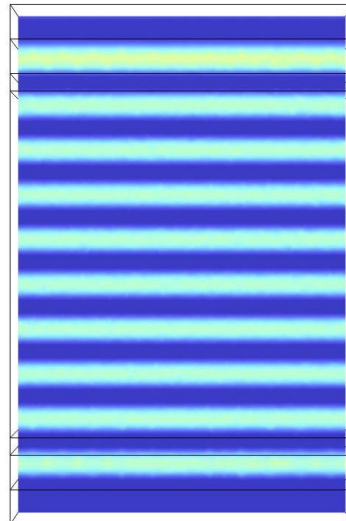
Plot of $|E|^2$ at $\lambda = 950$ nm

- SU-8 FLiSS host
- AlInP cube (size 200 nm, height 300 nm) as FLiSS structure

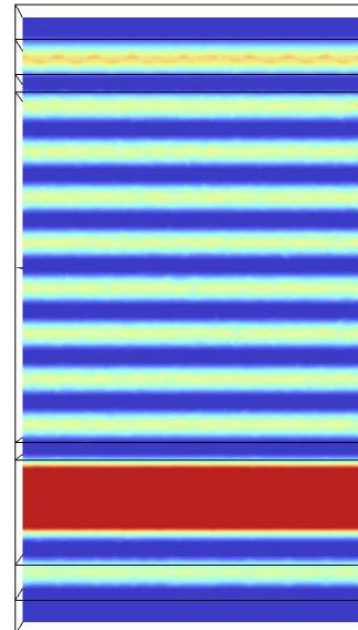
z (vertical position)



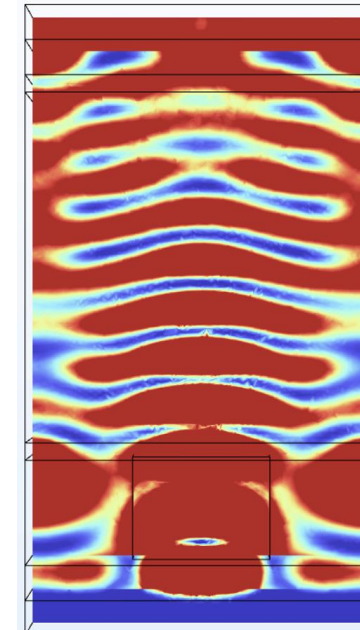
Add Al_{0.8}Ga_{0.2}As window layer



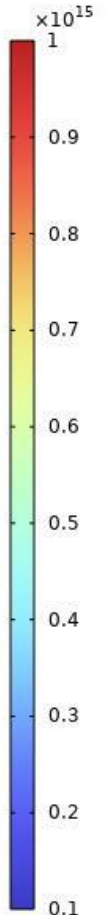
Add Al_{0.3}Ga_{0.7}As BSF



Add SU-8 FLiSS host



Add AlInP cube FLiSS structure



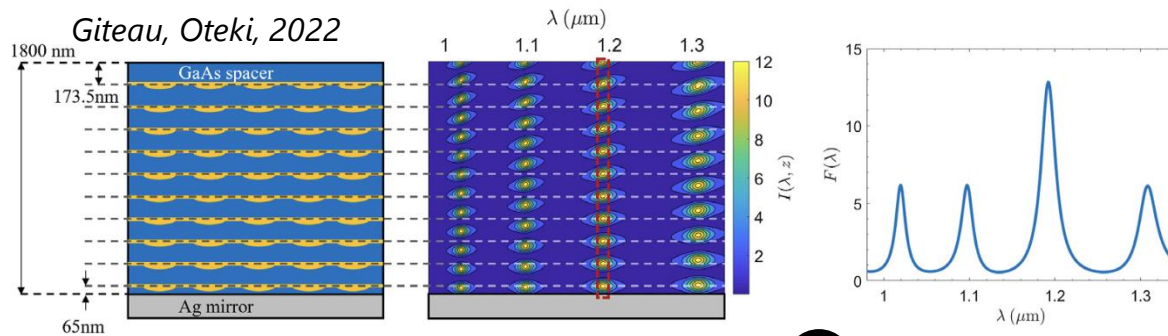
One choice of λ is not representative but:

- In general for almost all wavelengths, the FLiSS structure **enhances** and **distorts** the distribution of **the E-field**.
- However, there is a small displacement of the resonance wavelengths.

2- First simulation results

Position of the resonance wavelengths

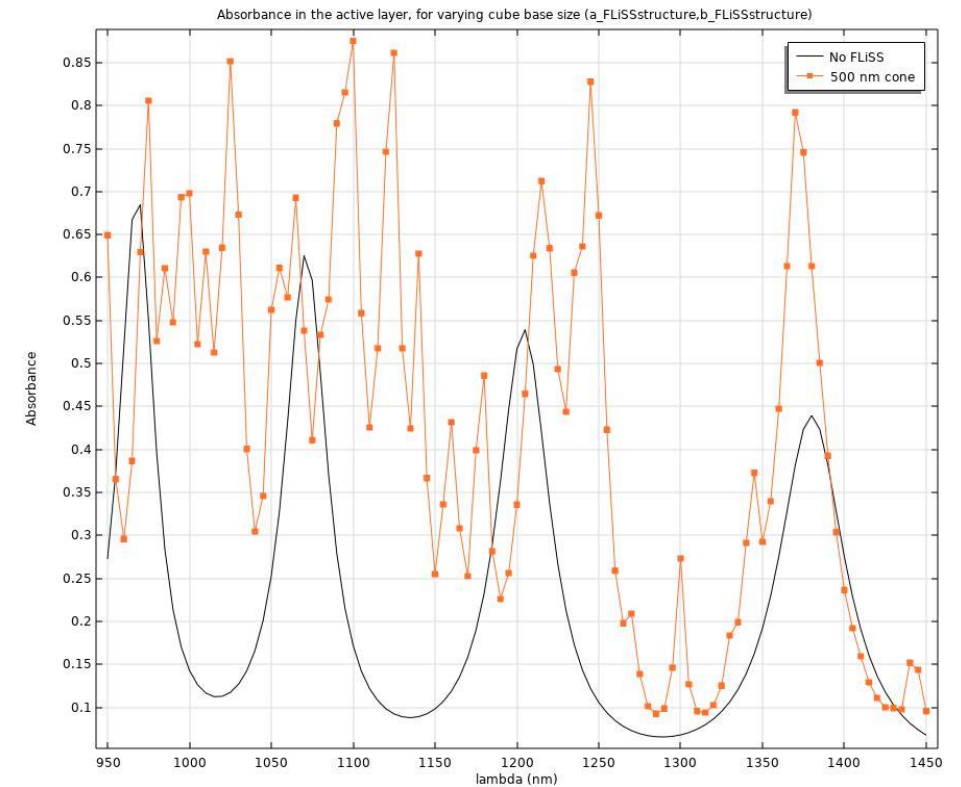
Expectations: (FP resonance)



1 Resonance wavelengths

2 At these wavelengths, peaks and nodes depending on vertical position z

1 **Absorption in active layer** - Comparison with or without the FLISS



Resonance wavelengths are still observed but their position is modified due to the FLISS.

2- First simulation results

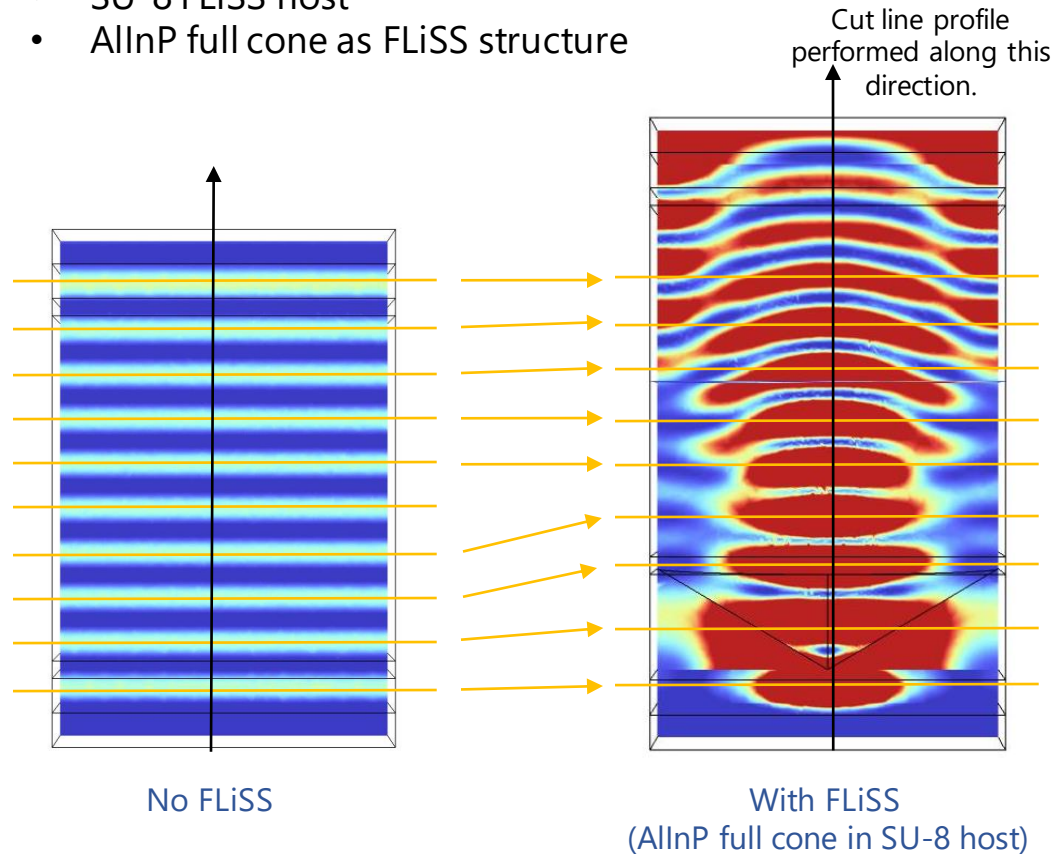
At fixed wavelength, position of the E-field peaks

2

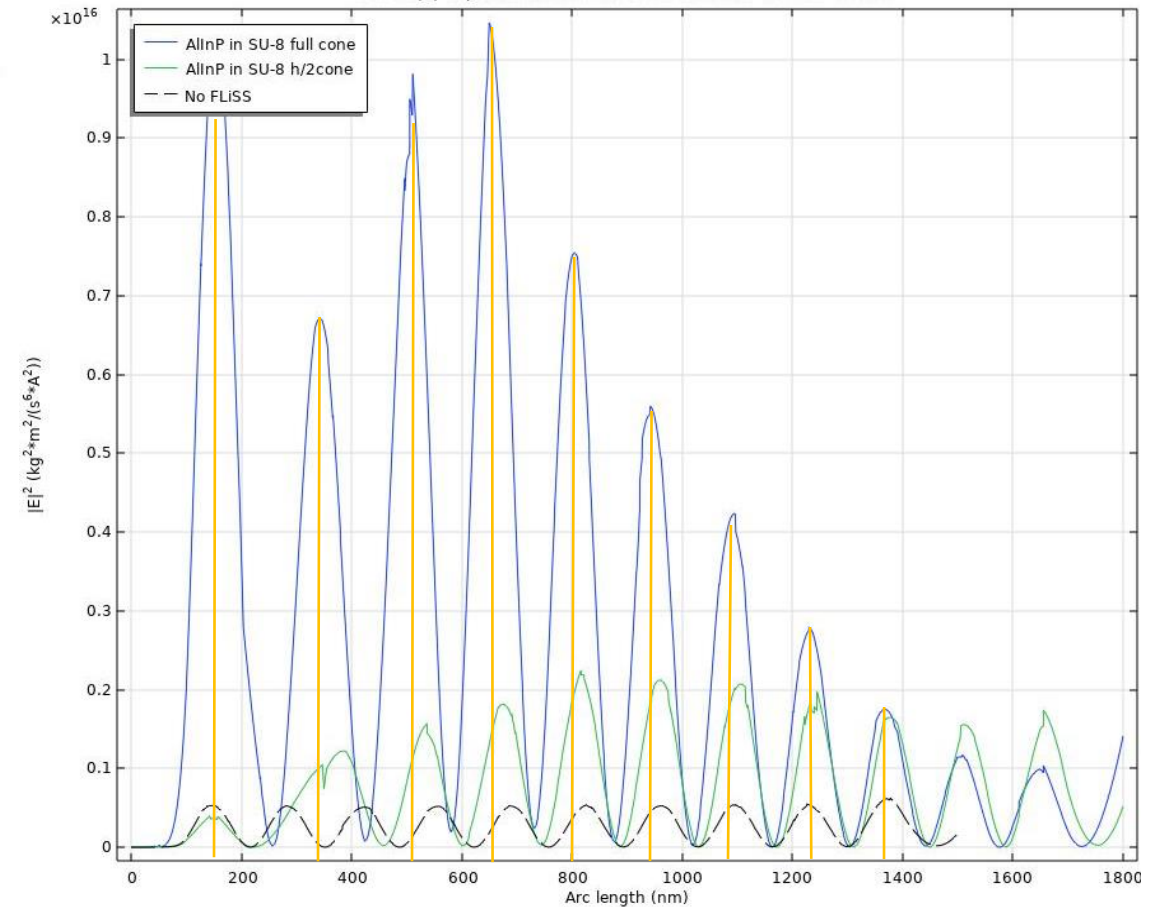
Example

Plot of $|E|^2$ at $\lambda = 950$ nm

- SU-8 FLiSS host
- AlInP full cone as FLiSS structure



Cut line profile $|E|^2$ at $\lambda = 950$ nm



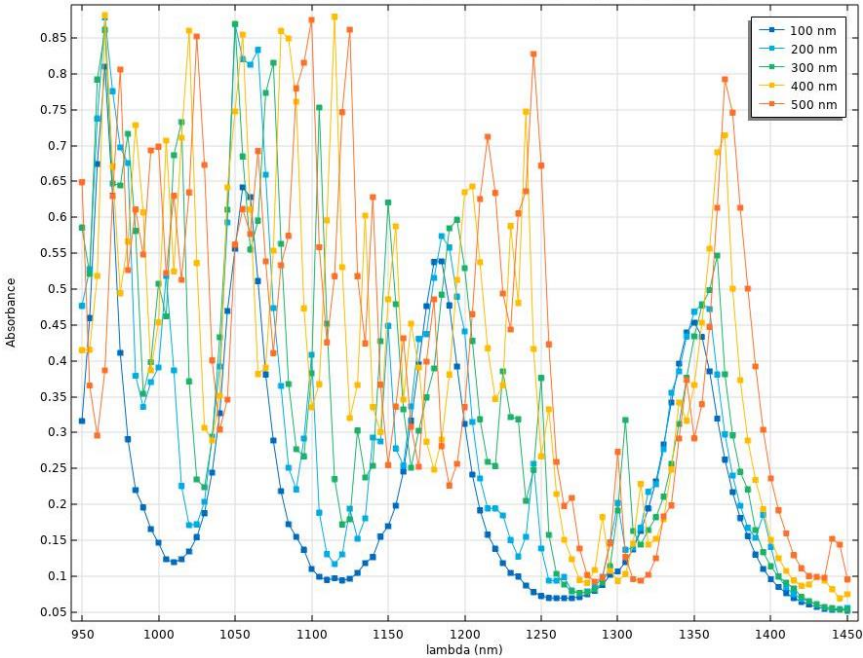
For each wavelength, **position and number of the resonance peaks is changed** when adding the light-scattering structure.

- For a chosen FLiSS (shape, size), the position of the QD layers can be optimized accordingly after choosing one wavelength of interest.

3- Parametric studies

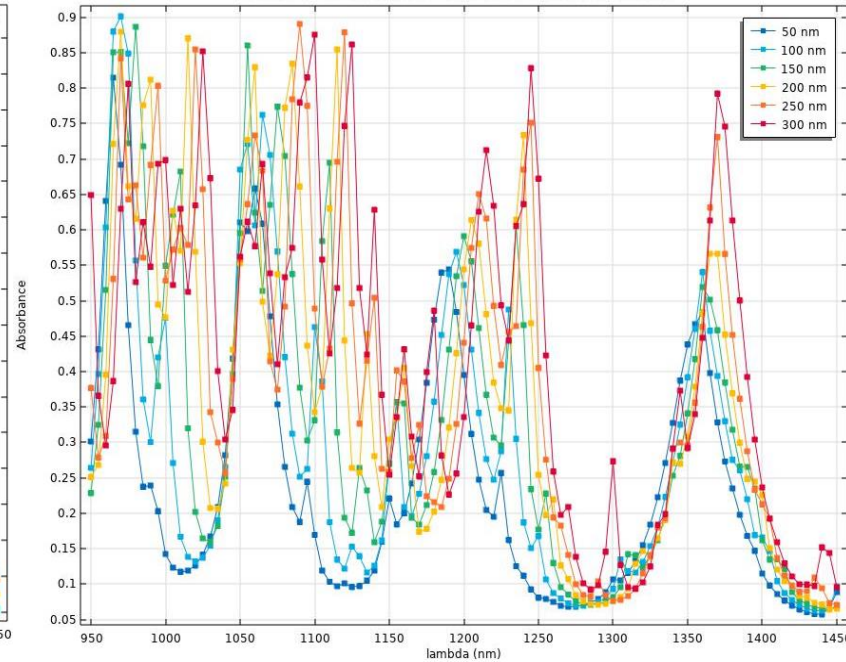
Absorption in the active layer – Cone pattern

Changing the radius of the cone



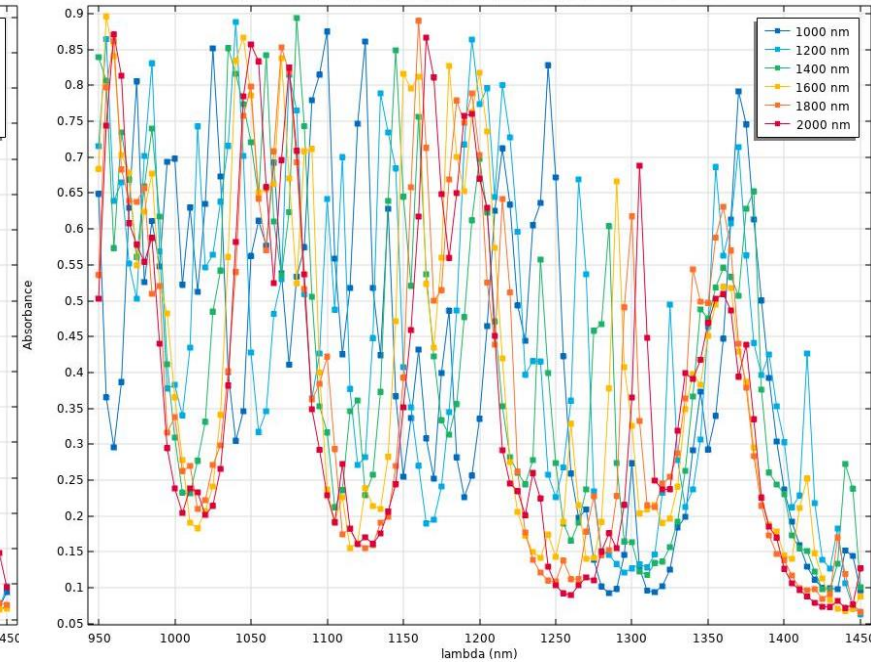
Absorption is higher when the **radius** of the FLiSS cone is **larger**.

Changing the height of the cone



Absorption is higher when the **height** of the FLiSS cone is **larger**.

Changing the pattern periodicity



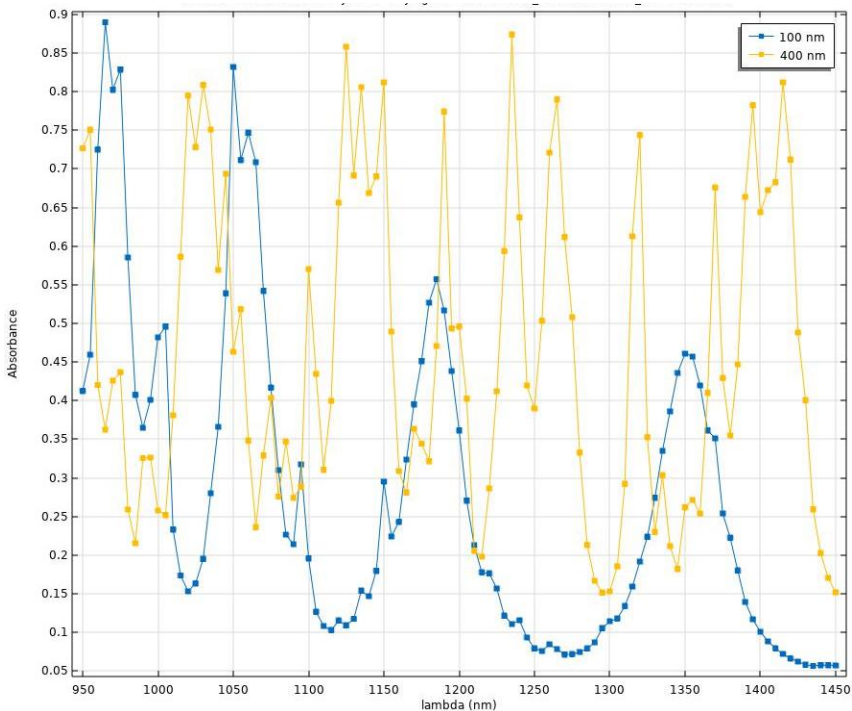
Absorption is higher when the **periodicity** of the pattern is **lower**.

- The data seems **noisy** but this reflects the complexity of the light-scattering.
- The denser the pattern, the more complex and the higher this scattering.

3- Parametric studies

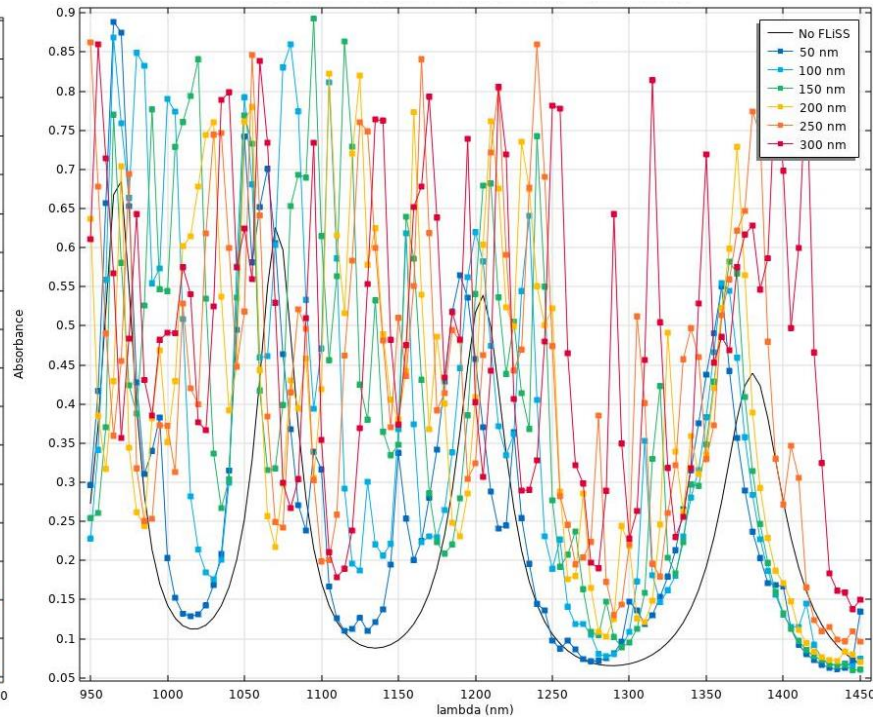
Absorption in the active layer – Cube pattern

Changing the square base size of the cone



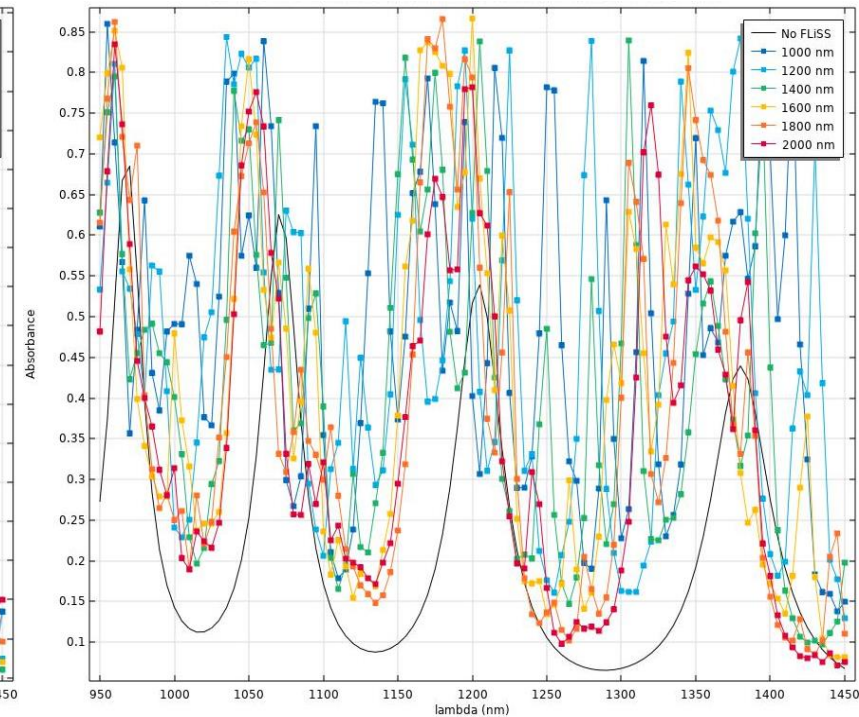
Absorption is higher when the **square size** of the FLiSS cube is **between 200 and 400 nm**.

Changing the height of the cube



Absorption is higher when the **height** of the FLiSS cube is **larger**.

Changing the pattern periodicity

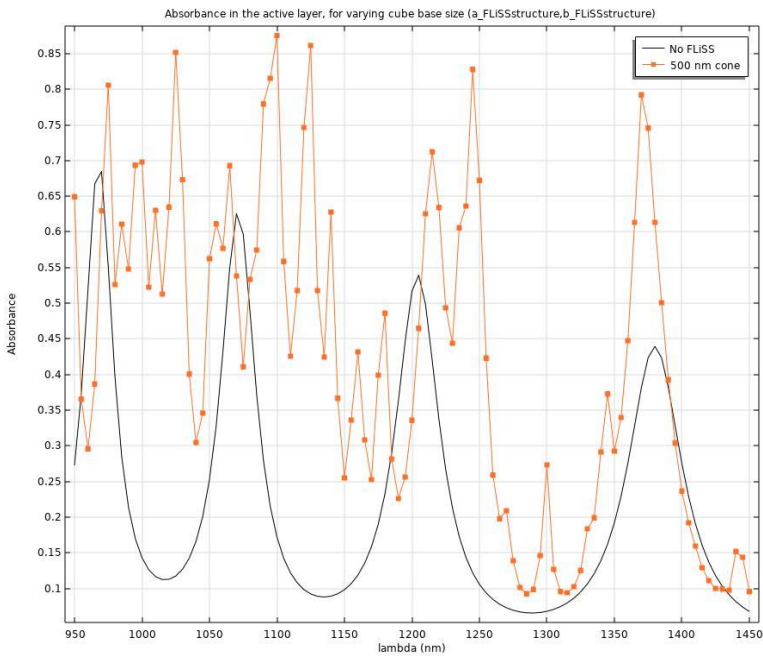


Absorption is higher when the **periodicity** of the pattern is **lower**.

- The data seems **noisy** as well but this is the light-scattering.
- The denser the pattern but with a medium size, the more complex and the higher this scattering.

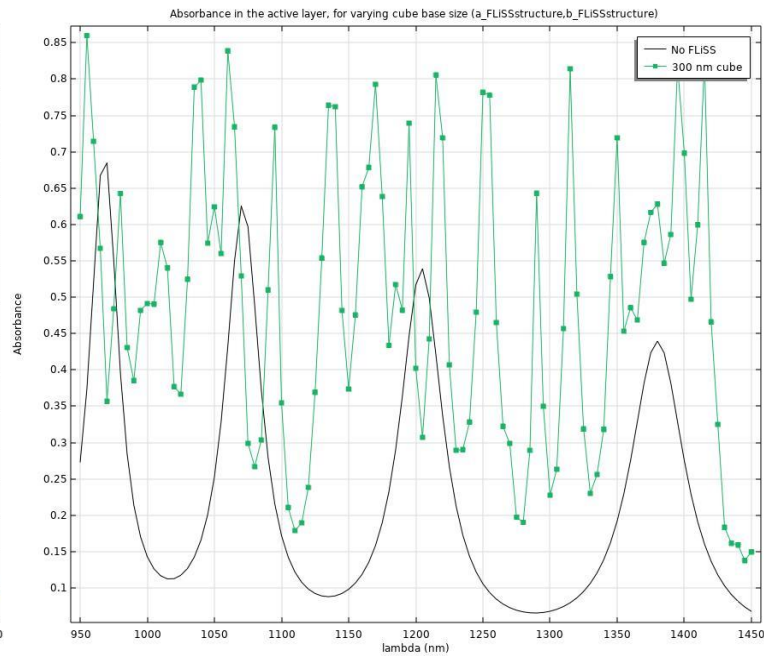
3- Parametric studies

Comparison cone vs cube FLiSS



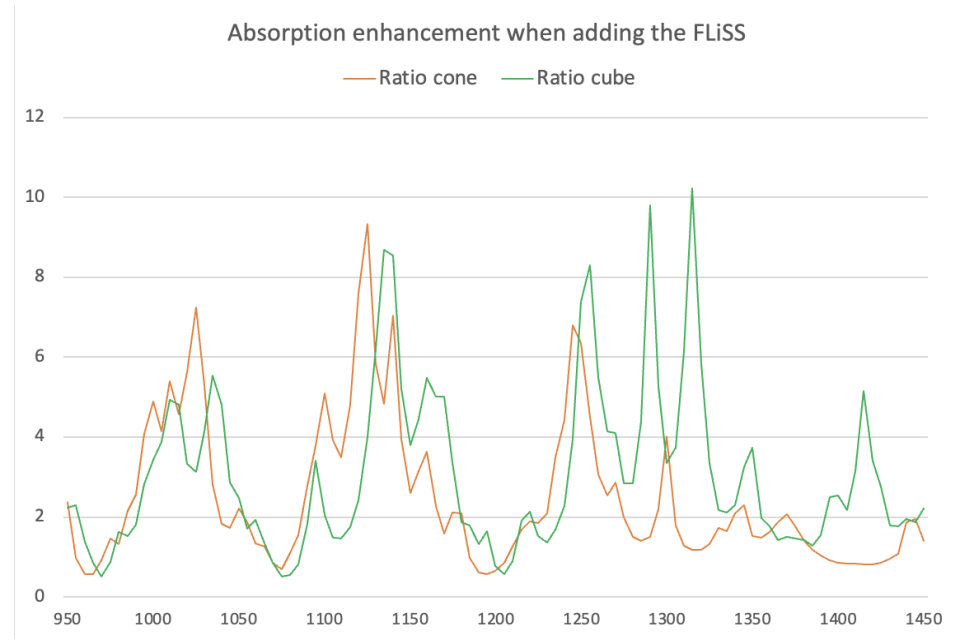
Absorption

FLiSS **cone** (radius 500 nm and height 300 nm) VS no FLiSS



Absorption

FLiSS **cube** (square 300 nm and height 300 nm) VS no FLiSS



Absorption enhancement

FLiSS **cone** (radius 500 nm and height 300 nm) VS FLiSS **cube** (square 300 nm and height 300 nm)

- As targeted, **increased absorption with the FLiSS**, for almost all wavelengths.
- For now, difficult to compare between best cube and cone FLiSS.

Summary

Results:

- High, large FLISS cone results in the highest absorption.
- Try even higher values?
- High, medium sized cube results in the highest absorption.
- Hard to compare between cone and cube for now.

Problems:

- Find good meshing for calculations in finite elements on Comsol.
- Find more accurate refractive indexes for AlInP and SU-8 with wavelength dependency.

Next:

- Add quantum dots and solar incident spectrum in the model.
- Do finer simulations around the interesting values.